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# 2SK3070(L), 2SK3070(S)

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1063-0900

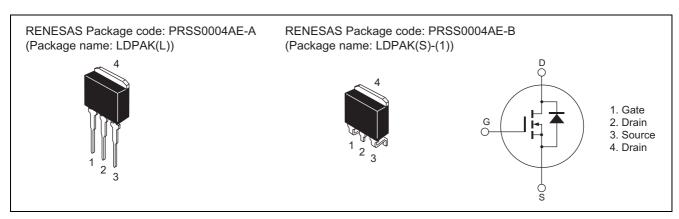
(Previous: ADE-208-684G)

Rev.9.00 Sep 07, 2005

### **Features**

- Low on-resistance  $R_{DS(on)} = 4.5 \text{ m}\Omega \text{ typ.}$
- Low drive current
- 4 V gate drive device can be driven from 5 V source

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	40	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	75	А
Drain peak current	I <sub>D(pulse)</sub> Note1	300	А
Body-drain diode reverse drain current	I <sub>DR</sub>	75	A
Avalanche current	I <sub>AP</sub> Note3	50	A
Avalanche energy	E <sub>AR</sub> Note3	333	mJ
Channel dissipation	Pch Note2	100	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	−55 to +150	°C

Notes: 1. PW  $\leq$  10 $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

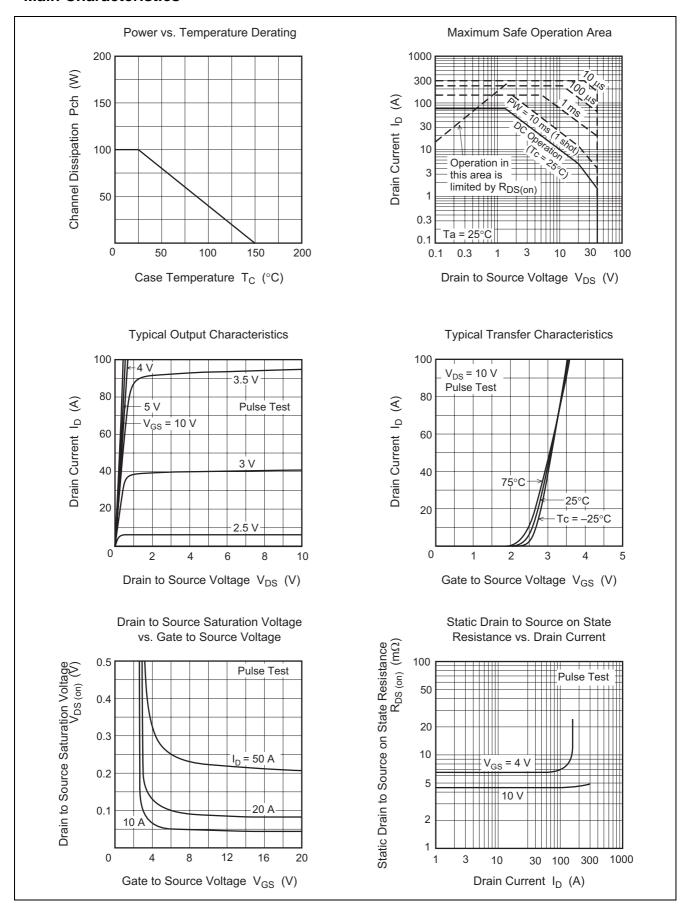
#### **Electrical Characteristics**

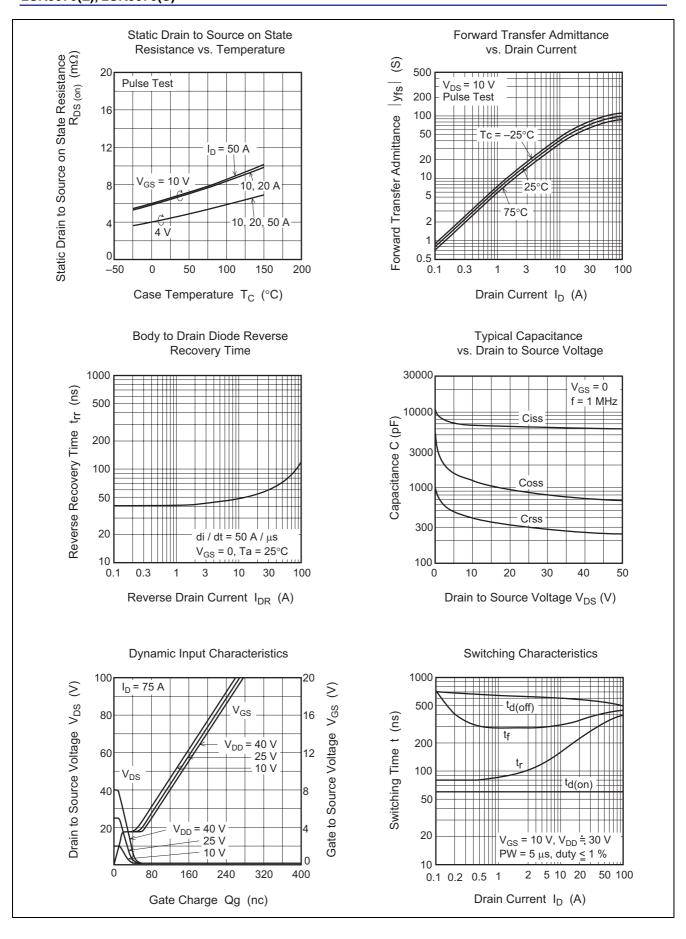
 $(Ta = 25^{\circ}C)$ 

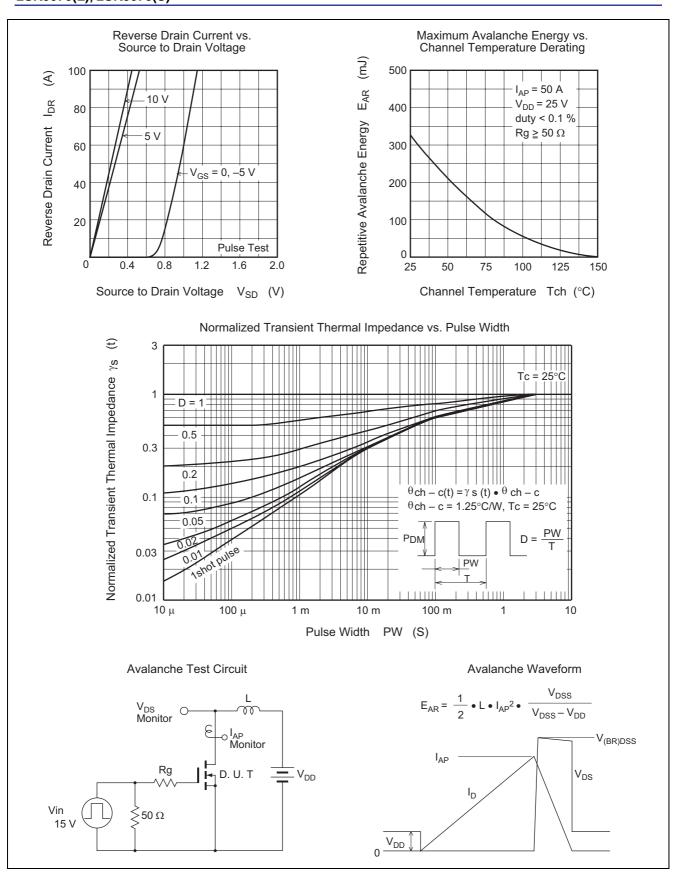
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	40	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	$I_{GSS}$	_	_	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 40 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{\text{Note}4}$
Static drain to source on state	R <sub>DS(on)</sub>	_	4.5	5.8	mΩ	$I_D = 40 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note}4}$
resistance		_	6.5	10	mΩ	$I_D = 40 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note}4}$
Forward transfer admittance	y <sub>fs</sub>	50	80	_	S	$I_D = 40 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note}4}$
Input capacitance	Ciss	_	6800	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$
Output capacitance	Coss	_	1300	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	380	_	pF	
Total gate charge	Qg	_	130	_	nC	$V_{DD} = 25 \text{ V}, V_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	25	_	nC	$I_D = 75 A$
Gate to drain charge	Qgd	_	30	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	60		ns	$V_{GS} = 10 \text{ V}, I_D = 40 \text{ A},$
Rise time	t <sub>r</sub>	_	300		ns	$R_L = 0.75 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	550	_	ns	
Fall time	t <sub>f</sub>	_	400	_	ns	
Body-drain diode forward voltage	$V_{DF}$	_	1.05		V	$I_F = 75 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery	t <sub>rr</sub>	_	90		ns	$I_F = 75 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 50 A/ \mu s$

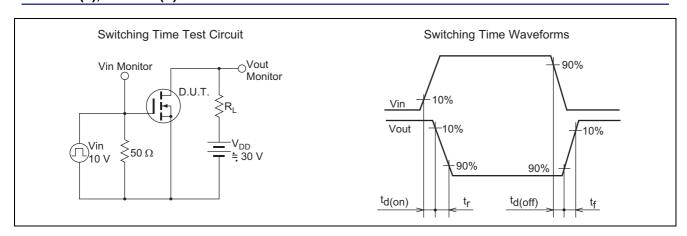
Note: 4. Pulse test

#### **Main Characteristics**

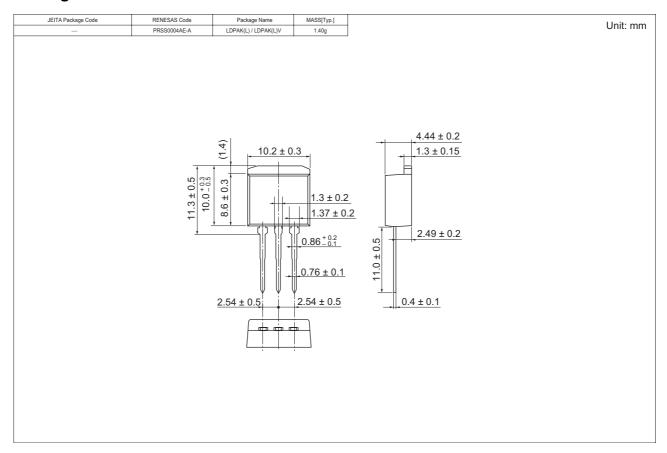


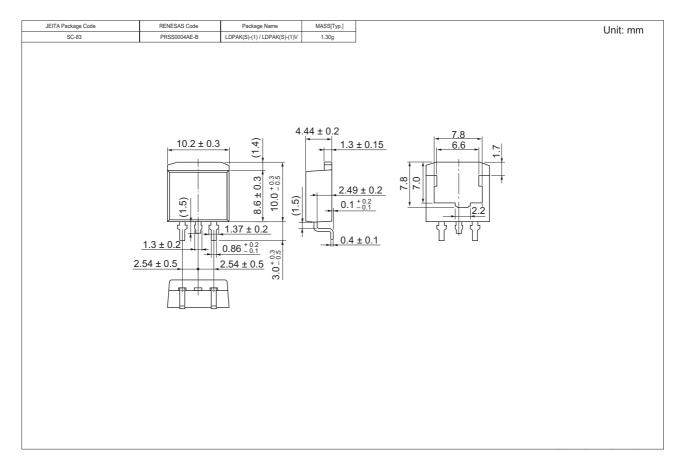






## **Package Dimensions**





## **Ordering Information**

Part Name	Quantity	Shipping Container
2SK3070L-E	500 pcs	Box (Tube)
2SK3070STL-E	500 pcs	Taping

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